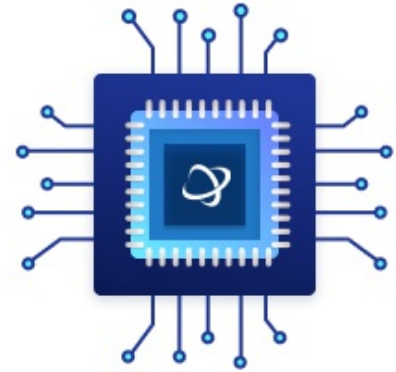


Lateral N-Channel Broadband RF Power MOSFET, 1.8-600 MHz, 300 W, 50 V

Manufacturers	NXP Semiconductor
Package/Case	NI-780-4
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for MRFE6VP6300HR3 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.



General Description

Features

Lateral N-Channel Broadband RF Power MOSFET, 1.8-600 MHz, 300 W, 50 V

Related Products



[MRFE6S9125NR1](#)

NXP Semiconductor
TO-270



[MRF6S20010GNR1](#)

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NI-360-3



[MRF8P20100HSR3](#)

NXP Semiconductor
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[MRF8P20160HSR3](#)

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[MRF6VP2600HR6](#)

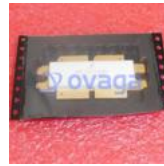
NXP Semiconductor
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